

The crystal Zero Degree Detector (cZDD) at BESIII

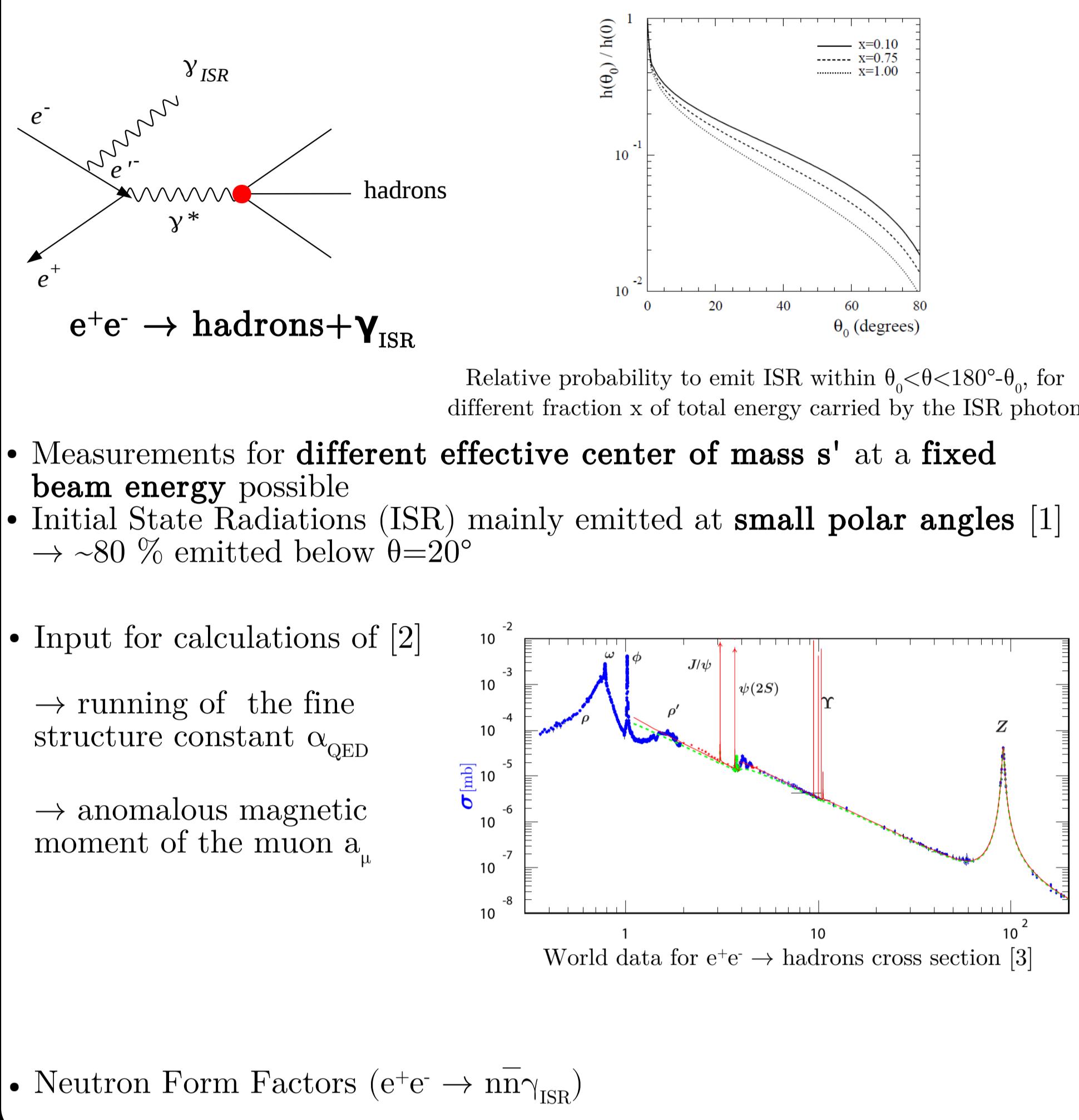
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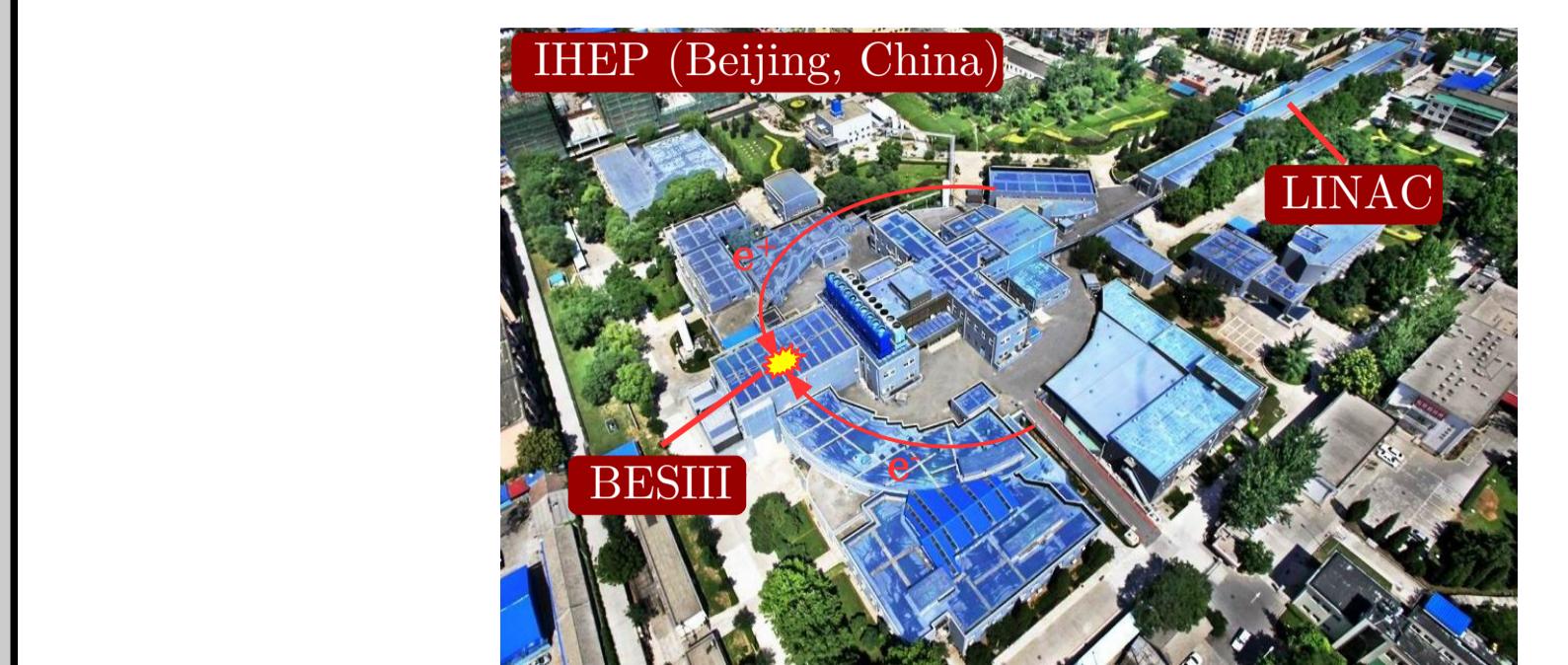
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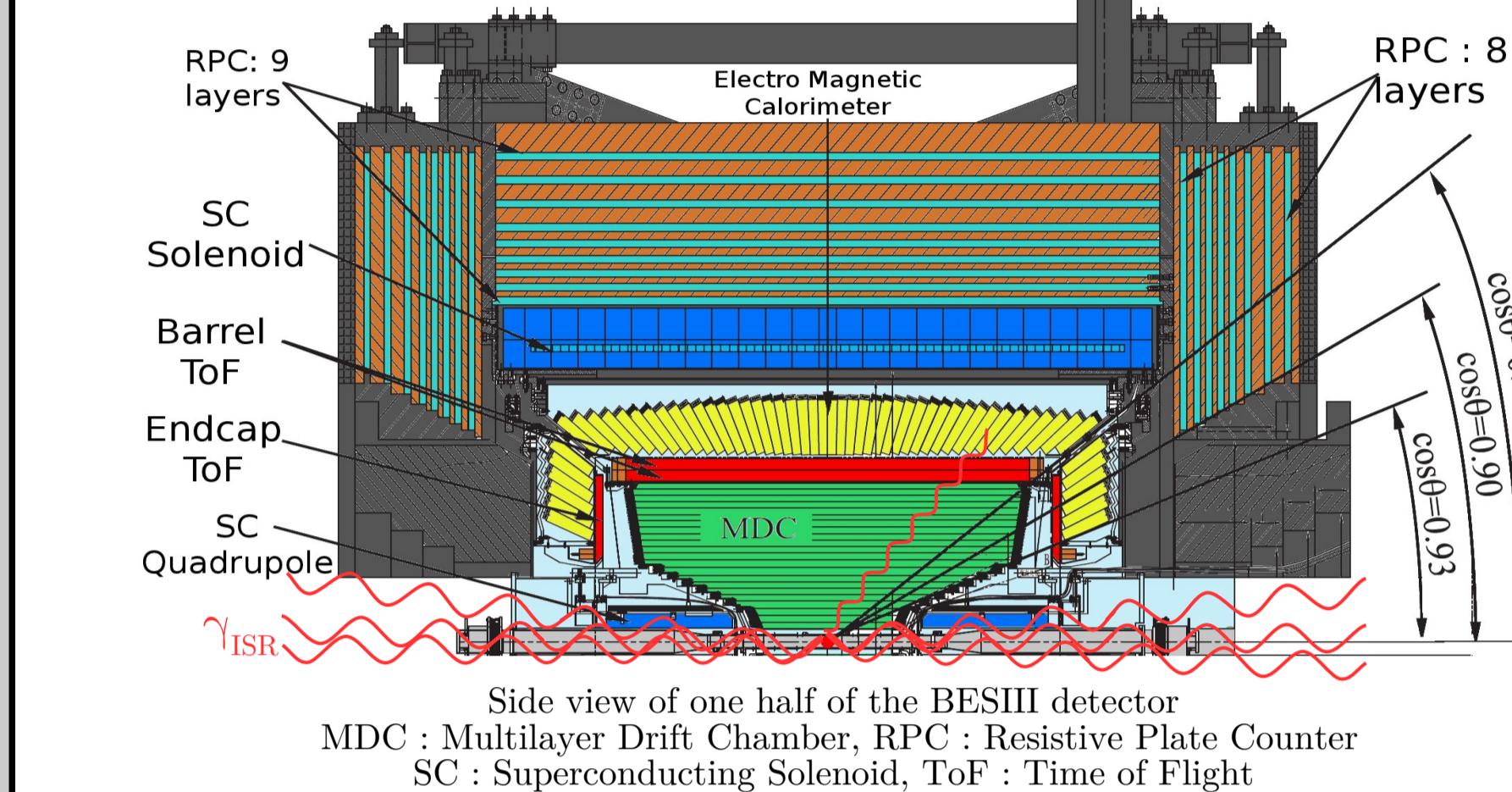
Physics motivation



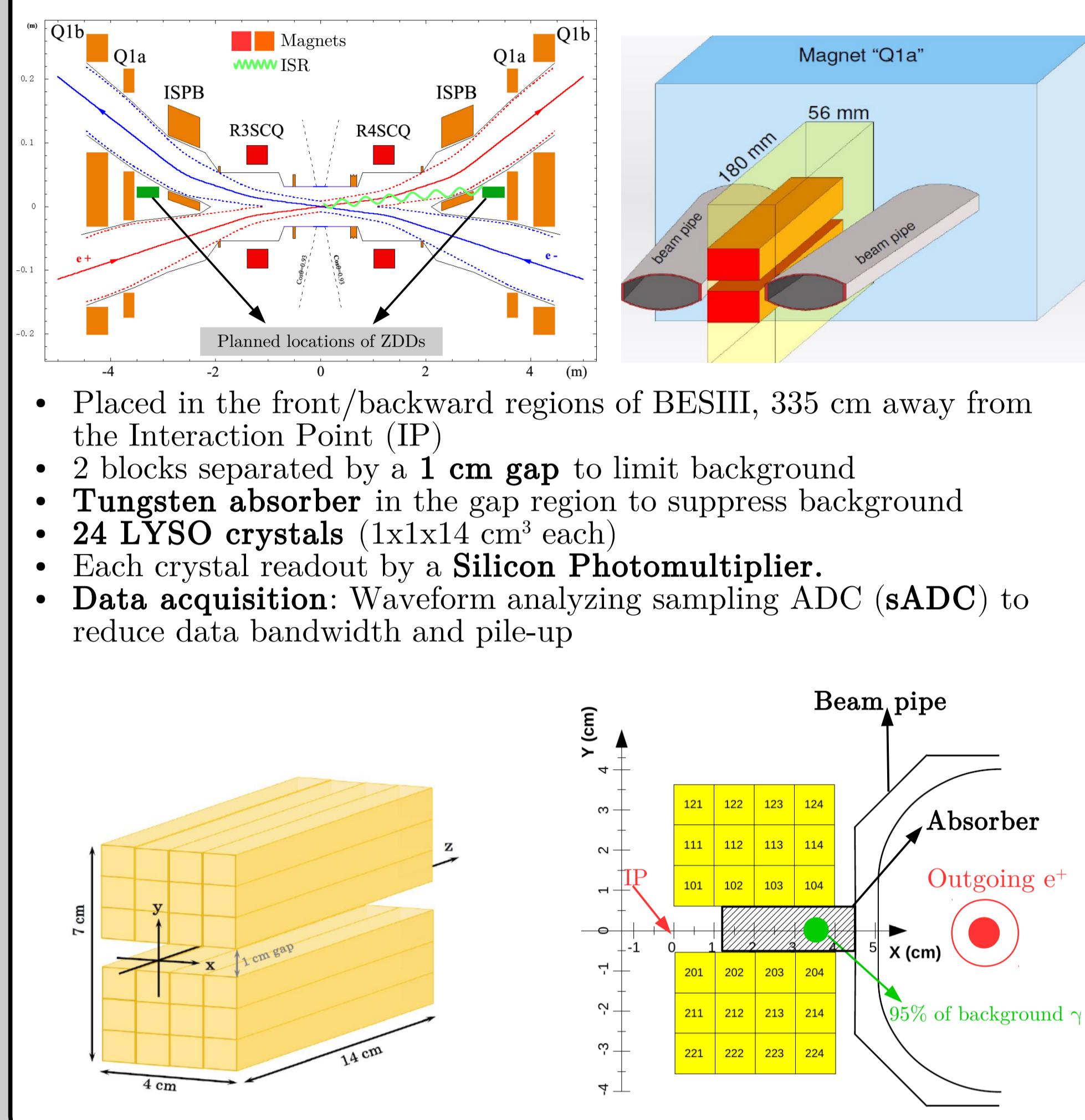
The BESIII experiment



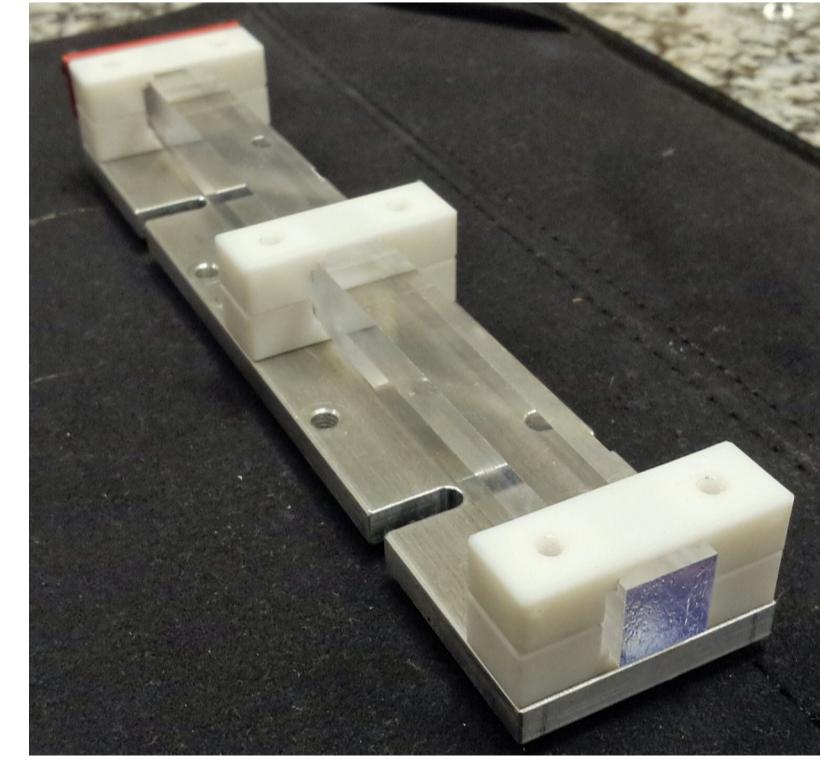
- BEPCII : Symmetric double ring, multi-bunch e^+e^- collider
- Center of mass energy = 2 - 4.6 GeV (Charm- τ) [4]
- Design luminosity achieved : $10^{33} \text{ cm}^{-2} \cdot \text{s}^{-1}$ at $E_{\text{CM}}=3.773 \text{ GeV}$



The cZDD

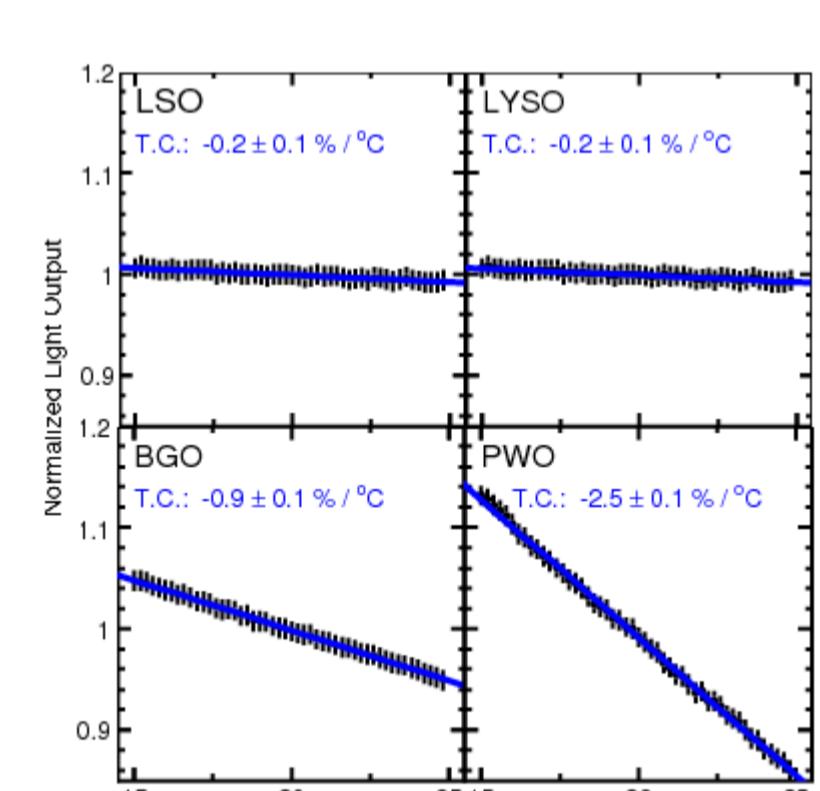


The LYSO crystal

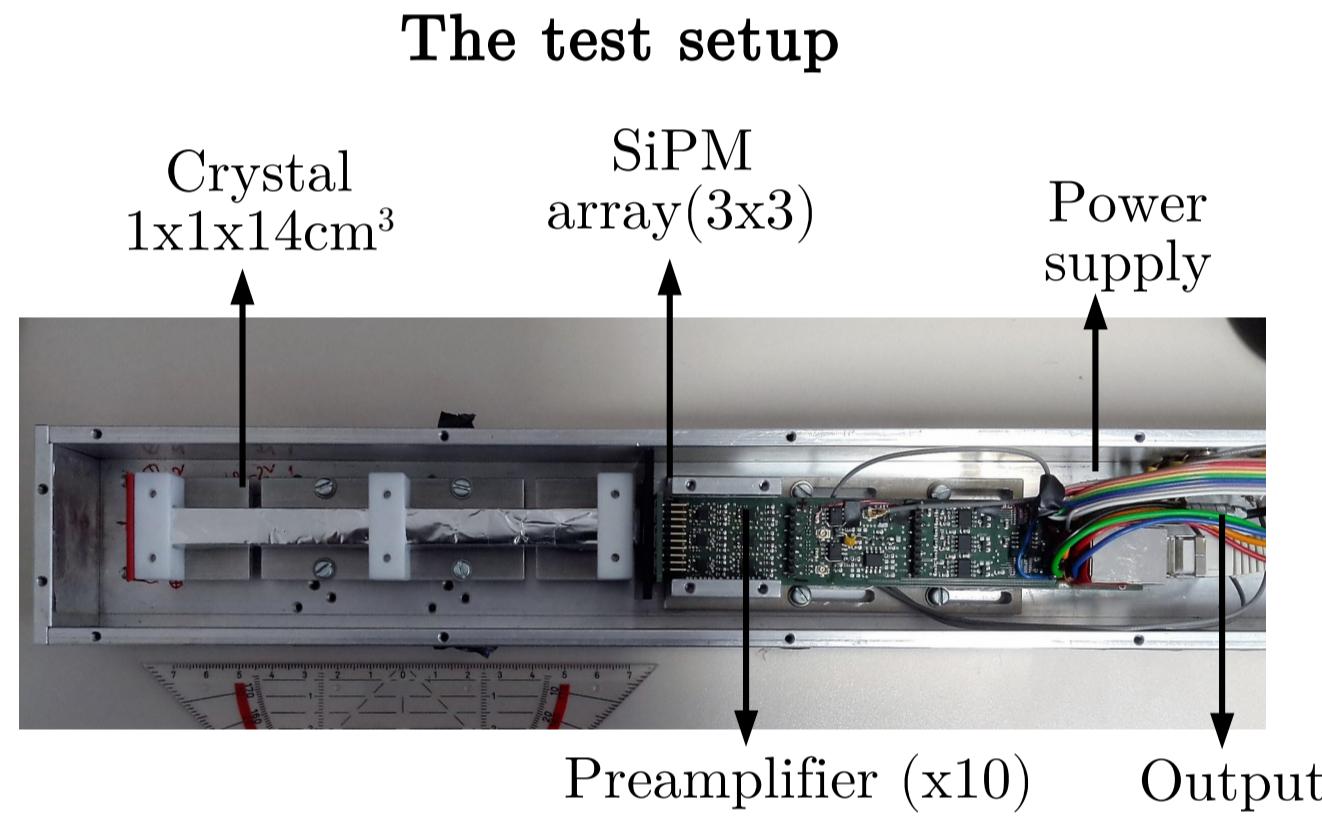


Density (g/cm ³)	7.15
Radiation Length(cm)	1.16
Decay Constant (ns)	<47
Peak Emission (nm)	410
Light Yield ($10^3 \text{ ph}/\text{MeV}$)	24.7-28.5
Energy Resolution (%)	8.9
Molière Radius (cm)	2-2.2

- $\text{Lu}_{1.8}\text{Y}_{0.2}\text{SiO}_5:\text{Ce}$ (EQ Photonics)
- High density inorganic crystal → Short radiation length.
- Radiation hardness
- Short decay constant → Limits pile-up from scintillations
- High light-yield → Low gain readout can be used.
- Stable light-yield at ambient temperature → High temperatures expected
- Radioactive → Self-emission of scintillation light

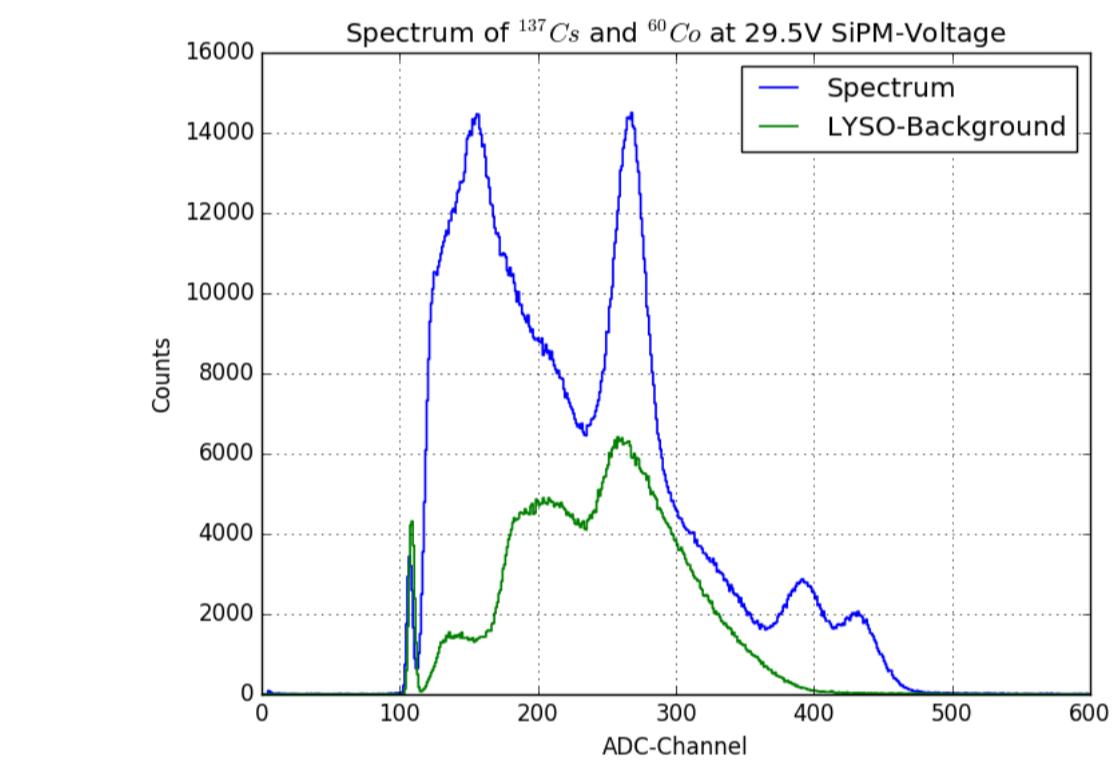


Test with single crystal prototype [5]



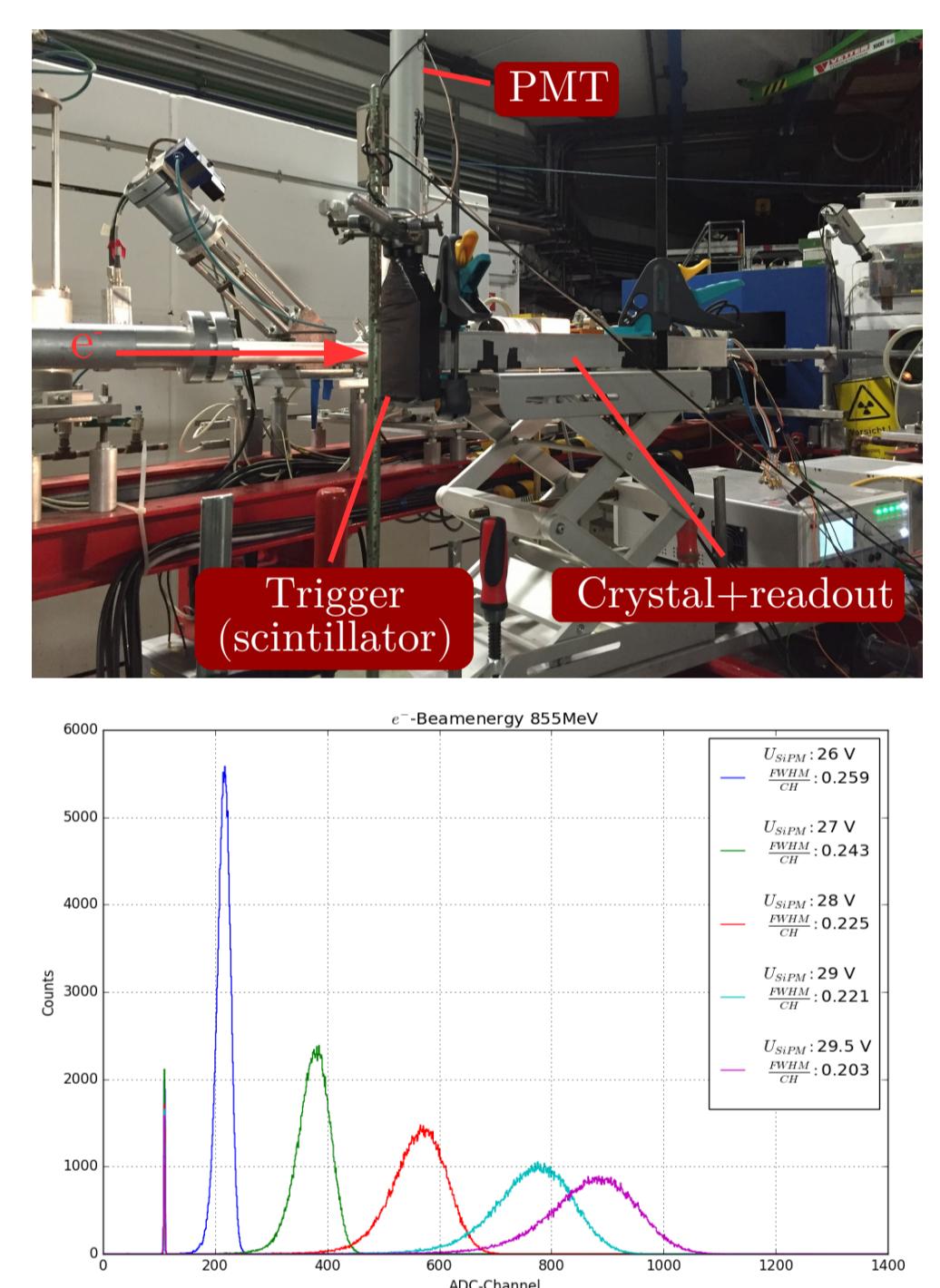
- Example of an inverted Waveform from one SiPM
- Self-triggered acquisition by an ADC
- Undershoot of the fast out signal → Signal is partly integrated → Gate has to be adjusted → Baseline offset needed

Measurements with ^{137}Cs and ^{60}Co



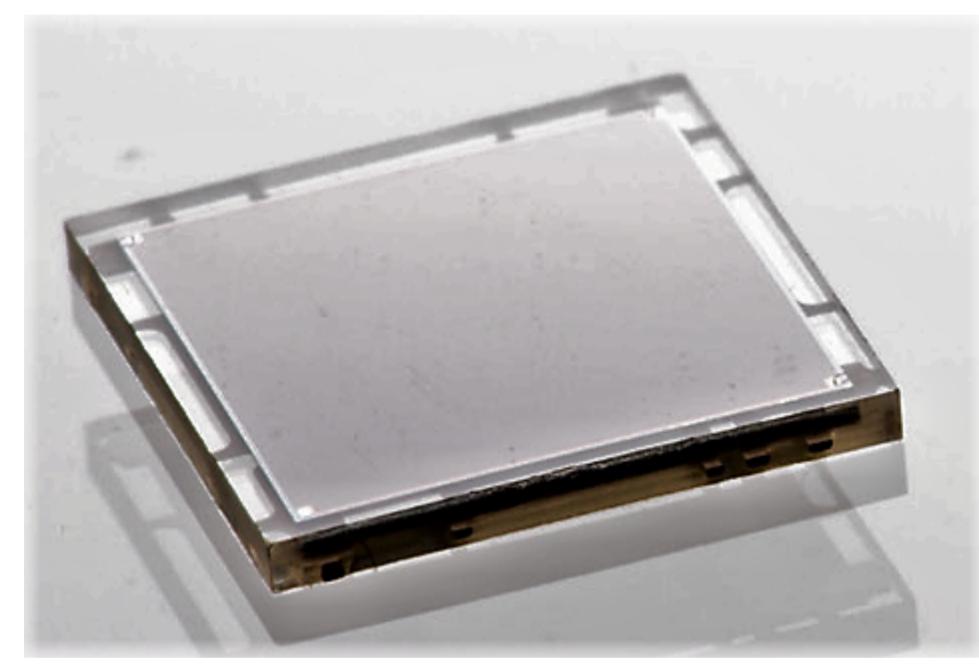
- ^{137}Cs and ^{60}Co peaks clearly visible
- Background from LYSO to be subtracted.
- Thermally induced compression of the spectrum
- Warm-up of the setup during measurements due to the readout board (T=25°C to 40°C)

Beam test at MAMI facility



- Electron beam : f=1 kHz, E=195/855 MeV
- Relative resolution improved with higher SiPM voltage

Silicon Photomultipliers (SiPMs)

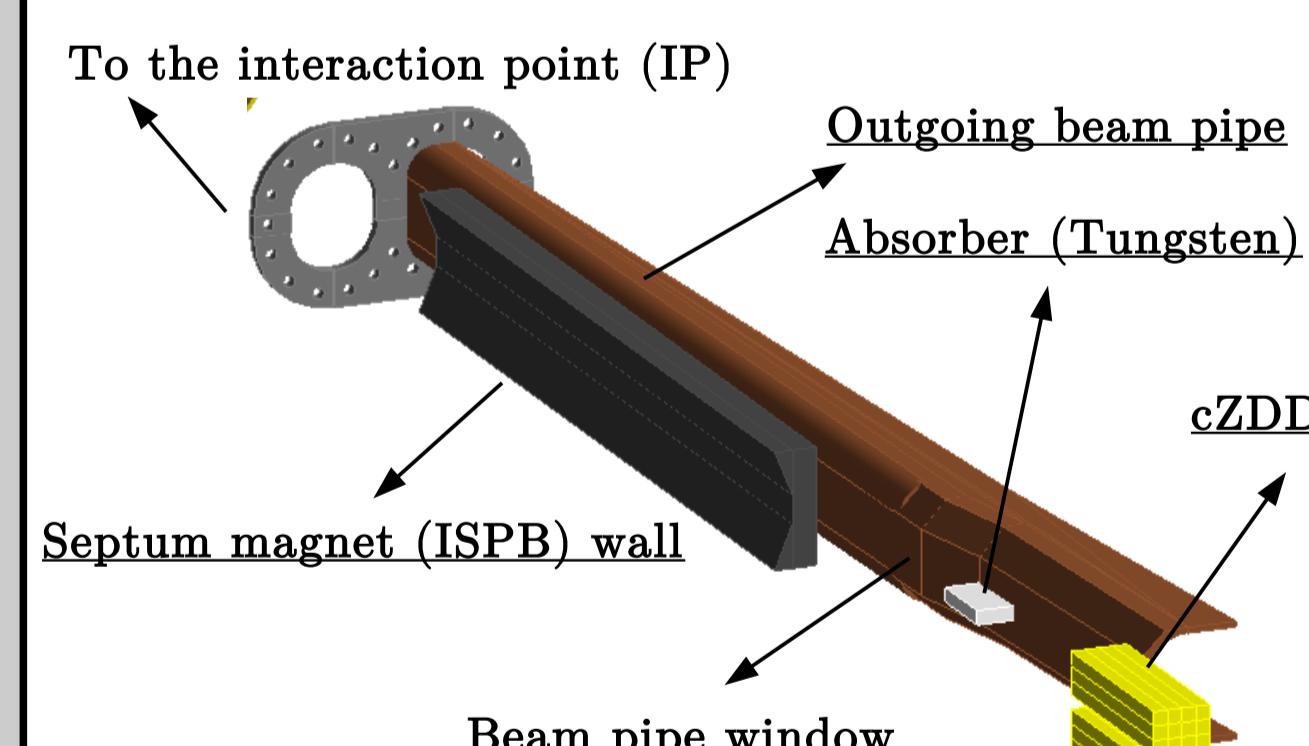


Crystal-Array
Electronic

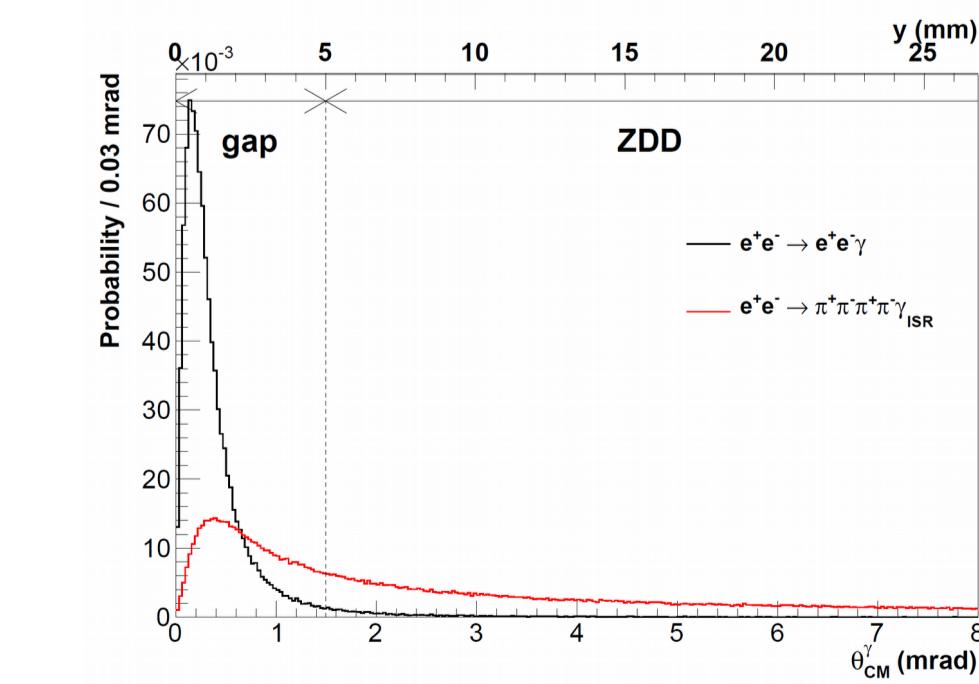
- SiPM used : SensL C series
- Advantages of SiPMs :
 - Compact
 - Inensitive to magnetic field
- Two outputs with different pulse width :
 - Slow (FWHM=200 ns)
 - Fast (FWHM~3 ns)

Sensor Size (mm ²)	6x6
Breakdown Voltage U_{br} (V)	24.2-24.7
Recommend overvoltage (V)	1.0-5.0
Peak Wavelength (nm)	420
No. of pixels	18980
Gain (Fast Output) at $U_{\text{br}} + 2.5\text{V}$	4.3×10^4

Simulations

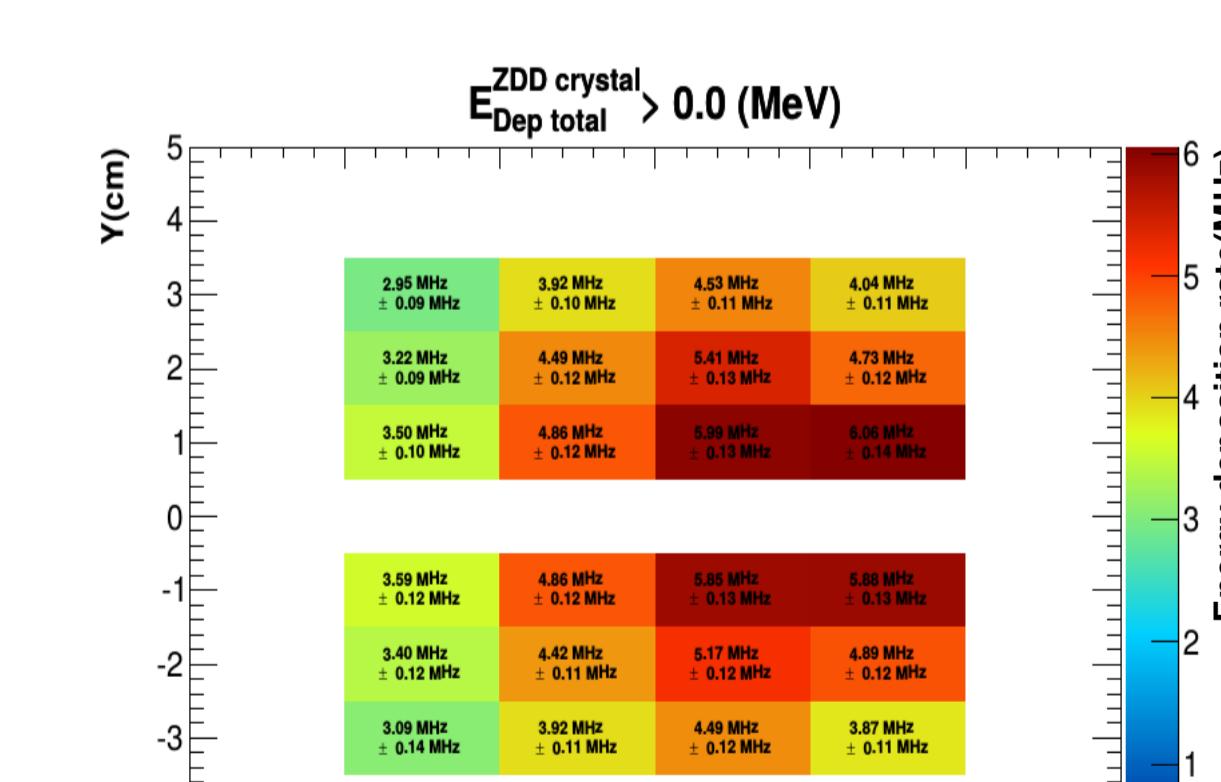


- Geant4-based simulation of BESIII and the two beam pipes region.
- Simulation of cZDD includes geometry, propagation of the scintillation light and digitization of the signal [6].
- ISR photons pass from IP to the ZDD through the beam window.
- Secondary photons produced while ISR passes through the beam pipe wall



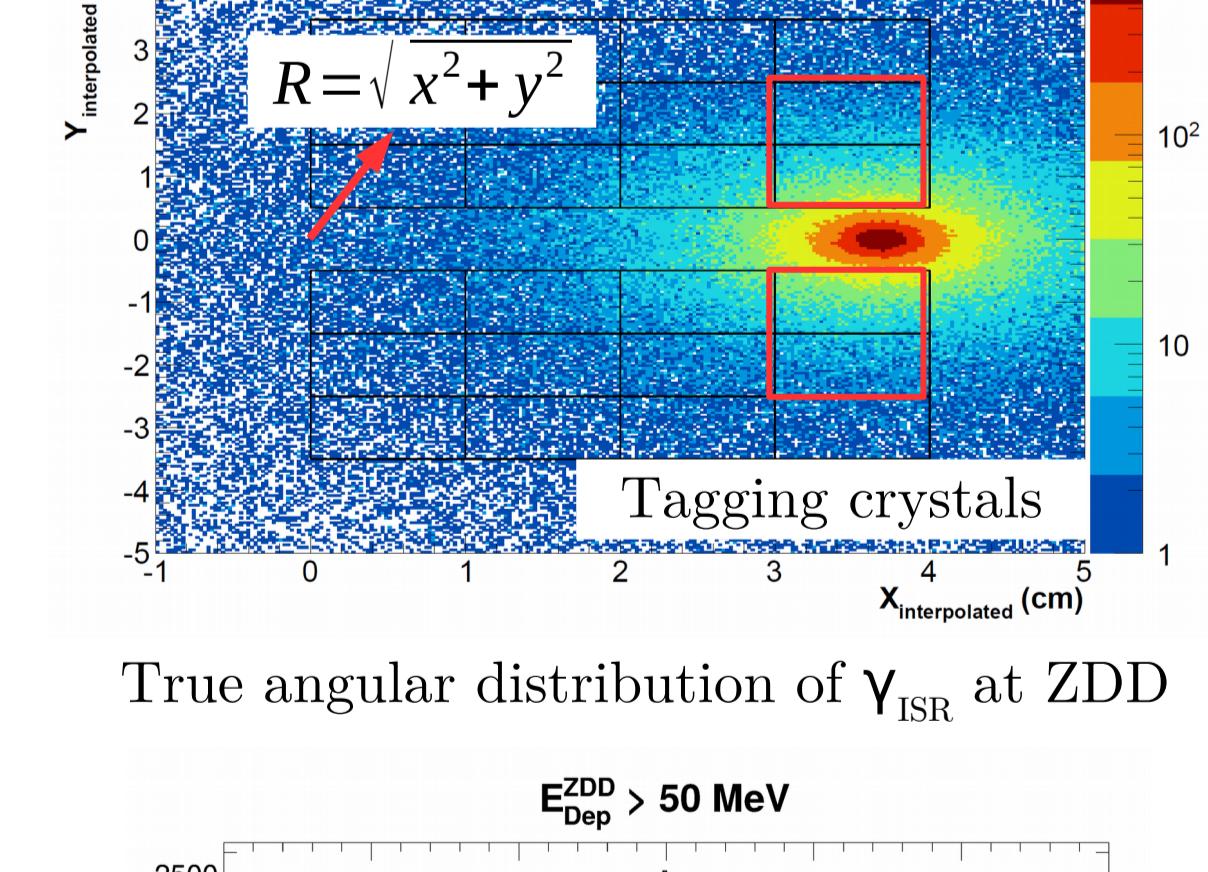
$e^+e^- \rightarrow e^+e^-\gamma$ background study

- Main contributing background at low polar angle
- $\sigma = 440 \text{ mb}$ ($E_{\text{CM}}=3.773 \text{ GeV}$, $E > 50 \text{ MeV}$) [7]



- The gap limits radiative Bhabha ($e^+e^- \rightarrow e^+e^-\gamma$) → More than 95 % background γ in the gap.
- Maximal energy deposition rate in one crystal :
 - Without absorber : $f_{\text{max}}=20 \text{ MHz}$
 - With absorber : $f_{\text{max}}=6 \text{ MHz} < 1/\tau_{\text{Scintillation}} \sim 25 \text{ MHz}$

γ_{ISR} hit reconstruction in $e^+e^- \rightarrow \pi^+\pi^-\pi^+\pi^-\gamma_{\text{ISR}}$



- Significant improvement on radial position with tagged photon over the missing 4 vector.

Summary and outlooks

- Improvement on ISR coverage
- Significant improvement on the resolution of ISR kinematics
- Beam pipe materials limits the tagging coverage
- Test of the prototype with full DAQ chain using high intensity photon beam at MAMI A2

References

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- [6] M.Werner, PhD Thesis, Justus-Liebig Universität Gießen (2015)
- [7] R.Kleiss et al., Comp.Phys.Comm., **81**, 3 (1994)